

Single Phase Rectifier Bridge

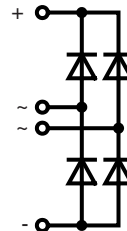
$I_{dAV} = 38 \text{ A}$
 $V_{RRM} = 800-1200 \text{ V}$

Standard and Avalanche Types

Replacement: VBO25-12/16NO2 resp. VBO25-16AO2

V_{RSM} V	V_{BRmin} ① V	V_{RRM} V	Standard Types	Avalanche Types
900		800	VBO 25-08NO2	
1300	1230	1200		VBO 25-12AO2

① For Avalanche Type only



Symbol	Conditions	Maximum Ratings	
I_{dAV} ②	$T_C = 85^\circ\text{C}$, module	38	A
I_{dAVM}	module	40	A
P_{RSM}	$T_{VJ} = T_{VJM}$	3.4	kW
I_{FSM}	$T_{VJ} = 45^\circ\text{C}$; $V_R = 0$	$t = 10 \text{ ms}$ (50 Hz)	370 A
		$t = 8.3 \text{ ms}$ (60 Hz)	390 A
	$T_{VJ} = T_{VJM}$; $V_R = 0$	$t = 10 \text{ ms}$ (50 Hz)	320 A
		$t = 8.3 \text{ ms}$ (60 Hz)	340 A
I^2t	$T_{VJ} = 45^\circ\text{C}$; $V_R = 0$	$t = 10 \text{ ms}$ (50 Hz)	680 A ² s
		$t = 8.3 \text{ ms}$ (60 Hz)	640 A ² s
	$T_{VJ} = T_{VJM}$; $V_R = 0$	$t = 10 \text{ ms}$ (50 Hz)	510 A ² s
		$t = 8.3 \text{ ms}$ (60 Hz)	470 A ² s
T_{VJ}		-40...+150 °C	
T_{VJM}		150 °C	
T_{stg}		-40...+125 °C	
V_{ISOL}	50/60 Hz, RMS $t = 1 \text{ min}$ $I_{ISOL} \leq 1 \text{ mA}$ $t = 1 \text{ s}$	3000	V~
		3600	V~
M_d	Mounting torque (M5) (10-32 UNF)	1.5-2	Nm
		13-18	lb.in.
Weight	Typ.	15	g

Features

- Avalanche rated parts available
- Package with DCB ceramic base plate
- Isolation voltage 3600 V~
- Planar passivated chips
- Low forward voltage drop
- ¼" fast-on terminals
- UL registered E 72873

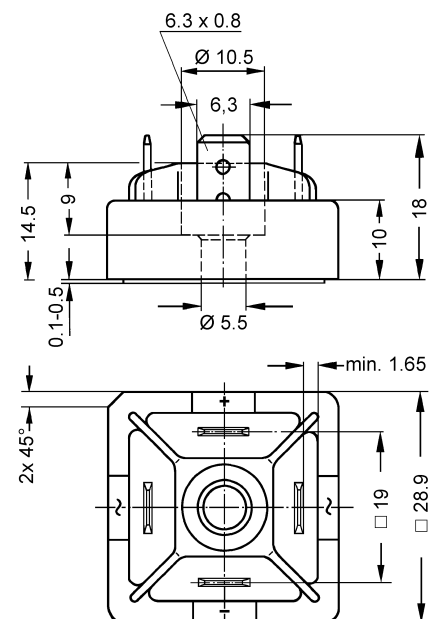
Applications

- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Advantages

- Easy to mount with one screw
- Space and weight savings
- Improved temperature & power cycling

Dimensions in mm (1 mm = 0.0394")



Symbol	Conditions	Characteristic Values	
I_R	$V_R = V_{RRM}$ $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = T_{VJM}$	0.3	mA
		5.0	mA
V_F	$I_F = 55 \text{ A}$ $T_{VJ} = 25^\circ\text{C}$	1.36	V
V_{TO}	For power-loss calculations only	0.85	V
r_t		8	mΩ
R_{thJC}	per diode; 120° el.	2.80	K/W
	per module	0.70	K/W
R_{thJH}	per diode; 120° el.	3.20	K/W
	per module	0.80	K/W
d_s	Creeping distance on surface	13	mm
d_a	Creepage distance in air ③	9.5	mm
a	Max. allowable acceleration	50	m/s ²

Data according to IEC 60747 and refer to a single diode unless otherwise stated.

② for resistive load at bridge output

③ with isolated fast-on tabs.

IXYS reserves the right to change limits, test conditions and dimensions.

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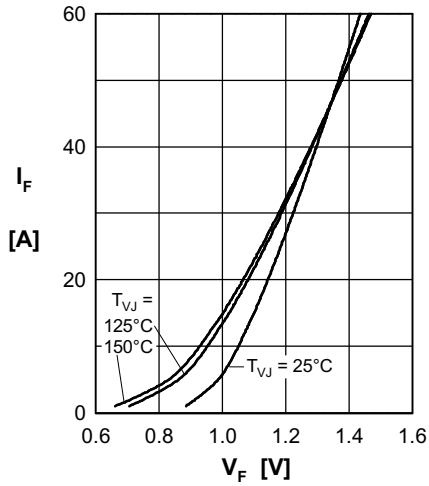


Fig. 1 Forward current vs. voltage drop per diode

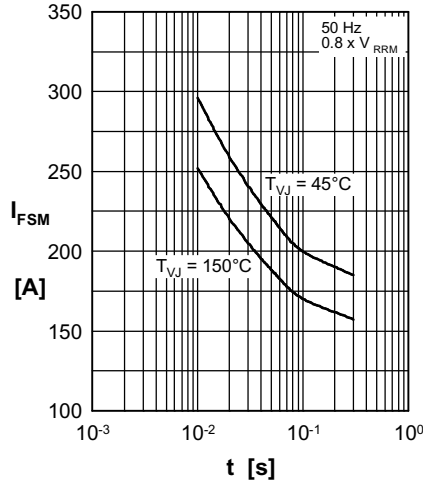


Fig. 2 Surge overload current vs. time per diode

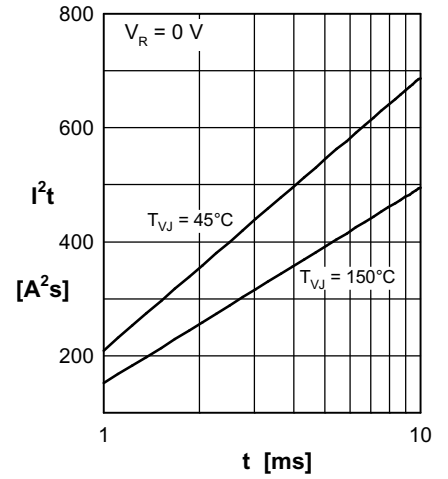


Fig. 3 I^2t vs. time per diode

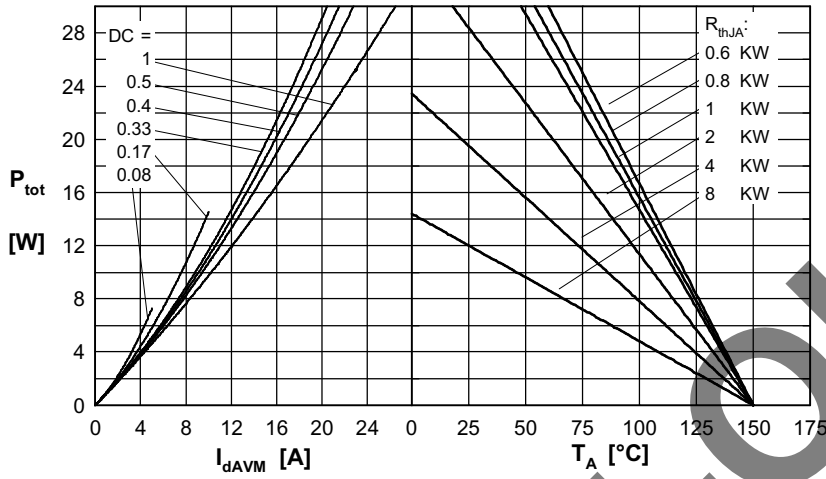


Fig. 4 Power dissipation vs. forward current and ambient temperature per diode

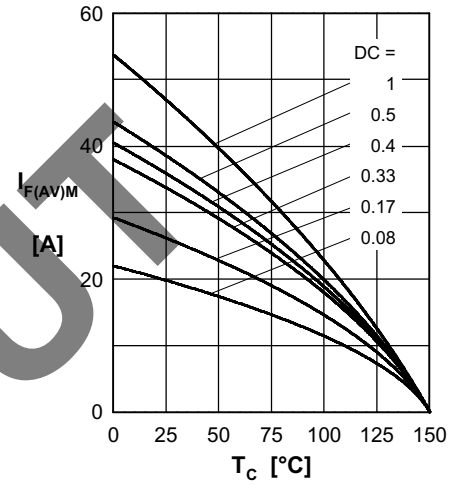


Fig. 5 Max. forward current vs. case temperature per diode

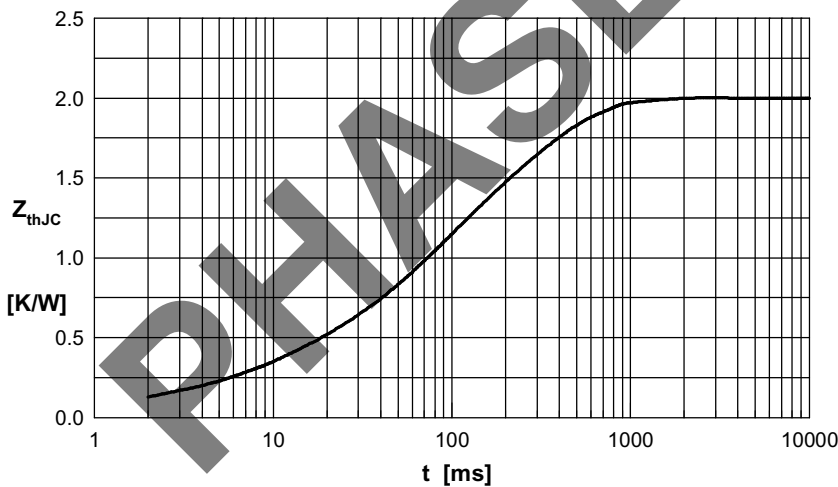


Fig. 6 Transient thermal impedance junction to case vs. time per diode

Constants for Z_{thJC} calculation:

i	R_{th} (K/W)	t_i (s)
1	0.061	0.001
2	0.203	0.008
3	0.500	0.250
4	0.703	0.060
5	0.533	0.300